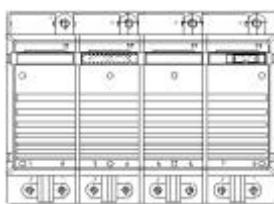


# SKiiP 132GDL120-4DU



**SKiiP® 2**

## 7-pack - integrated intelligent Power System

### Power section - 3 phase bridge

### SKiiP 132GDL120-4DU

### Features

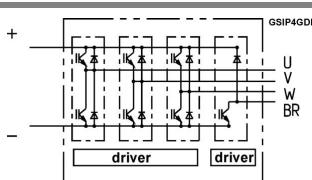
- SKiiP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP® 2 power section)
- UL recognized File no. E63532 (SKiiP® 2 power section)

1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)

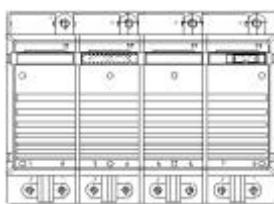
Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
$V_{CES}$		1200	V
$V_{CC}^1)$	Operating DC link voltage	900	V
$V_{GES}$		$\pm 20$	V
$I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	150 (112,5)	A
<b>Inverse diode</b>			
$I_F = -I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	150 (112,5)	A
$I_{FSM}$	$T_j = 150^\circ\text{C}$ , $t_p = 10 \text{ ms}$ ; sin.	1440	A
$I^2t$ (Diode)	Diode, $T_j = 150^\circ\text{C}$ , 10 ms	10	kA <sup>2</sup> s
$T_j$ ( $T_{stg}$ )		- 40 (- 25) ... + 150 (125)	°C
$V_{isol}$	AC, 1 min. (mainterminals to heat sink)	3000	V

Characteristics		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	min.	typ.	max.
<b>IGBT</b>				
$V_{CESat}$	$I_C = 125 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,6 (3,1)	3,1	V
$V_{CEO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,2 (1,3)	1,5 (1,6)	V
$r_{CE}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	10,5 (14)	12,6 (16,1)	mΩ
$I_{CES}$	$V_{GE} = 0 \text{ V}$ , $V_{CE} = V_{CES}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	(10)	0,4	mA
$E_{on} + E_{off}$	$I_C = 125 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$	38	mJ	
		66	mJ	
$R_{CC' + EE'}$	terminal chip, $T_j = 125^\circ\text{C}$	0,5		mΩ
$L_{CE}$	top, bottom	15		nH
$C_{CHC}$	per phase, AC-side	1,4		nF
<b>Inverse diode</b>				
$V_F = V_{EC}$	$I_F = 150 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,1 (1,9)	2,6	V
$V_{TO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,3 (1)	1,4 (1,1)	V
$r_T$	$T_j = 25 \text{ (125)}^\circ\text{C}$	5 (6)	6,8 (7,8)	mΩ
$E_{rr}$	$I_C = 125 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$	6	mJ	
		8	mJ	
<b>Mechanical data</b>				
$M_{dc}$	DC terminals, SI Units	6	8	Nm
$M_{ac}$	AC terminals, SI Units	13	15	Nm
w	SKiiP® 2 System w/o heat sink	3,5		kg
w	heat sink	8,5		kg
<b>Thermal characteristics (P16 heat sink; 275 m<sup>3</sup>/h); " <math>r</math> " reference to temperature sensor</b>				
$R_{th(j-s)I}$	per IGBT		0,18	K/W
$R_{th(j-s)D}$	per diode		0,375	K/W
$R_{th(s-a)}$	per module		0,036	K/W
$Z_{th}$	$R_i$ (mK/W) (max. values)		tau <sub>i</sub> (s)	
	1      2      3      4	1      2      3      4		
$Z_{th(j-r)I}$	20      139      22      0	1      0,13      0,001      1		
$Z_{th(j-r)D}$	41      289      45      0	1      0,13      0,001      1		
$Z_{th(r-a)}$	1,7      24      7,6      2,6	494      165      20      0,03		

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Case S 5



**SKiiP® 2**

## 7-pack - integrated intelligent Power System

**7-pack  
integrated gate driver - 3 phase bridge  
SKiiP 132GDL120-4DU**

### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 40/85/56 (SKiiP® 2 gate driver)

### Absolute Maximum Ratings

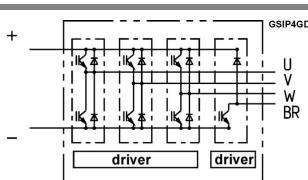
Symbol	Conditions	Values	Units
$V_{S1}$	stabilized 15 V power supply	18	V
$V_{S2}$	unstabilized 24 V power supply	30	V
$V_{iH}$	input signal voltage (high)	15 + 0,3	V
$dV/dt$	secondary to primary side	75	kV/μs
$V_{isolIO}$	input / output (AC, r.m.s., 2s)	3000	Vac
$V_{isol12}$	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac
$f_{max}$	switching frequency	20	kHz
$T_{op} (T_{stg})$	operating / storage temperature	- 40 ... + 85	°C

### Characteristics

Symbol	Conditions	min.	typ.	max.	Units
$V_{S1}$	supply voltage stabilized	14,4	15	15,6	V
$V_{S2}$	supply voltage non stabilized	20	24	30	V
$I_{S1}$	$V_{S1} = 15 \text{ V}$	$410 + 280 * f/f_{max} + 3,6 * (I_{AC}/A)$			mA
$I_{S2}$	$V_{S2} = 24 \text{ V}$	$300 + 200 * f/f_{max} + 2,6 * (I_{AC}/A)$			mA
$V_{iT+}$	input threshold voltage (High)	11,2			V
$V_{iT-}$	input threshold voltage (Low)			5,4	V
$R_{IN}$	input resistance	10			kΩ
$t_{d(on)IO}$	input-output turn-on propagation time			1,5	μs
$t_{d(off)IO}$	input-output turn-off propagation time			1,4	μs
$t_{pERRRESET}$	error memory reset time	9			μs
$t_{TD}$	top / bottom switch : interlock time		2,3		μs
$I_{analogOUT}$	8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V)	150			A
$I_{Vs1outmax}$	output current at pin 13/20/22/24/26			50	mA
$I_{A0max}$	logic low output voltage			5	mA
$V_{0L}$	logic high output voltage			0,6	V
$V_{0H}$				30	V
$I_{TRIPSC}$	over current trip level ( $I_{analog OUT} = 10 \text{ V}$ )	188			A
$I_{TRIPLG}$	ground fault protection	43			A
$T_{tp}$	over temperature protection	110		120	°C
$U_{DCTRIP}$	trip level of $U_{DC}$ -protection ( $U_{analog OUT} = 9 \text{ V}$ ); (option)	900			V

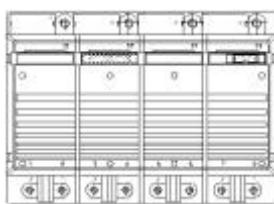
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Case S 5

# SKiiP 132GDL120-4DU



SKiiP® 2

## 7-pack - integrated intelligent Power System

### Power section - brake chopper

### SKiiP 132GDL120-4DU

### Features

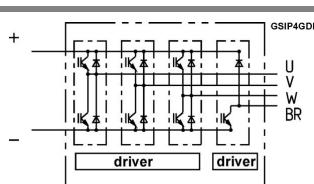
- SKiiP technology inside
- CAL diode technology
- Integrated current sensor
- Integrated temperature sensor
- Integrated heat sink
- IEC 60721-3-3 (humidity) class 3K3/IE32 (SKiiP® 2 System)
- IEC 68T.1 (climate) 40/125/56 (SKiiP® 2 power section)
- UL recognized File no. E63532 (SKiiP® 2 power section)

1) with assembly of suitable MKP capacitor per terminal (SEMIKRON type is recommended)

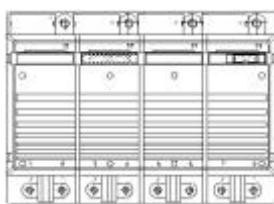
Absolute Maximum Ratings		$T_s = 25^\circ\text{C}$ unless otherwise specified	
Symbol	Conditions	Values	Units
<b>IGBT</b>			
$V_{CES}$		1200	V
$V_{CC}^1)$	Operating DC link voltage	900	V
$V_{GES}$		$\pm 20$	V
$I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	150 (112,5)	A
<b>Inverse diode</b>			
$I_F = -I_C$	$T_s = 25 \text{ (70)}^\circ\text{C}$	150 (112,5)	A
$I_{FSM}$	$T_j = 150^\circ\text{C}$ , $t_p = 10 \text{ ms}$ ; sin.	1440	A
$I^2t$ (Diode)	Diode, $T_j = 150^\circ\text{C}$ , 10 ms	10	kA²s
$T_j$ ( $T_{stg}$ )		- 40 (- 25) ... + 150 (125)	°C
$V_{isol}$	AC, 1 min. (mainterminals to heat sink)	3000	V

Characteristics		$T_s = 25^\circ\text{C}$ unless otherwise specified		
Symbol	Conditions	min.	typ.	max.
<b>IGBT</b>				
$V_{CESat}$	$I_C = 125 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,6 (3,1)	3,1	V
$V_{CEO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,2 (1,3)	1,5 (1,6)	V
$r_{CE}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	10,5 (14)	12,6 (16,1)	mΩ
$I_{CES}$	$V_{GE} = 0 \text{ V}$ , $V_{CE} = V_{CES}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	(10)	0,4	mA
$E_{on} + E_{off}$	$I_C = 125 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$	38	mJ	
		66	mJ	
$R_{CC' + EE'}$	terminal chip, $T_j = 125^\circ\text{C}$	0,5		mΩ
$L_{CE}$	top, bottom	15		nH
$C_{CHC}$	per phase, AC-side	1,4		nF
<b>Inverse diode</b>				
$V_F = V_{EC}$	$I_F = 150 \text{ A}$ , $T_j = 25 \text{ (125)}^\circ\text{C}$	2,1 (1,9)	2,6	V
$V_{TO}$	$T_j = 25 \text{ (125)}^\circ\text{C}$	1,3 (1)	1,4 (1,1)	V
$r_T$	$T_j = 25 \text{ (125)}^\circ\text{C}$	5 (6)	6,8 (7,8)	mΩ
$E_{rr}$	$I_C = 125 \text{ A}$ , $V_{CC} = 600 \text{ V}$ $T_j = 125^\circ\text{C}$ , $V_{CC} = 900 \text{ V}$	6	mJ	
		8	mJ	
<b>Mechanical data</b>				
$M_{dc}$	DC terminals, SI Units	6	8	Nm
$M_{ac}$	AC terminals, SI Units	13	15	Nm
w	SKiiP® 2 System w/o heat sink	3,5		kg
w	heat sink	8,5		kg
<b>Thermal characteristics (P16 heat sink; 275 m³/h); " <math>r</math> " reference to temperature sensor</b>				
$R_{th(j-s)I}$	per IGBT		0,18	K/W
$R_{th(j-s)D}$	per diode		0,375	K/W
$R_{th(s-a)}$	per module		0,036	K/W
$Z_{th}$	$R_i$ (mK/W) (max. values)		tau <sub>i</sub> (s)	
	1      2      3      4	1      2      3      4		
$Z_{th(j-r)I}$	20      139      22      0	1      0,13      0,001      1		
$Z_{th(j-r)D}$	41      289      45      0	1      0,13      0,001      1		
$Z_{th(r-a)}$	1,7      24      7,6      2,6	494      165      20      0,03		

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Case S 5



SKiiP® 2

## 7-pack - integrated intelligent Power System

### 7-pack gate driver - brake chopper

### SKiiP 132GDL120-4DU

#### Gate driver features

- CMOS compatible inputs
- Wide range power supply
- Integrated circuitry to sense phase current, heat sink temperature and DC-bus voltage (option)
- Short circuit protection
- Over current protection
- Over voltage protection (option)
- Power supply protected against under voltage
- Interlock of top/bottom switch
- Isolation by transformers
- Fibre optic interface (option for GB-types only)
- IEC 68T.1 (climate) 25/85/56 (SKiiP® 2 gate driver)

#### Absolute Maximum Ratings

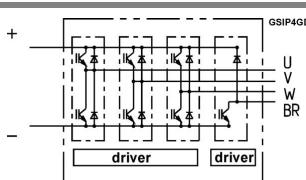
Symbol	Conditions	Values	Units
$V_{S1}$	stabilized 15 V power supply	18	V
$V_{S2}$	unstabilized 24 V power supply	30	V
$V_{iH}$	input signal voltage (high)	15 + 0,3	V
$dV/dt$	secondary to primary side	75	kV/μs
$V_{isolIO}$	input / output (AC, r.m.s., 2s)	3000	Vac
$V_{isol12}$	output 1 / output 2 (AC, r.m.s., 2s)	1500	Vac
$f_{max}$	switching frequency	5	kHz
$T_{op} (T_{stg})$	operating / storage temperature	- 25 ... + 85	°C

#### Characteristics

Symbol	Conditions	min.	typ.	max.	Units
$V_{S1}$	supply voltage stabilized	14,4	15	15,6	V
$V_{S2}$	supply voltage non stabilized	20	24	30	V
$I_{S1}$	$V_{S1} = 15 \text{ V}$	$67 + 10^* f/f_{max} + 0,0^*(I_{AC}/A)$			mA
$I_{S2}$	$V_{S2} = 24 \text{ V}$	$67 + 10^* f/f_{max} + 0,0^*(I_{AC}/A)$			mA
$V_{iT+}$	input threshold voltage (High)	11,2			V
$V_{iT-}$	input threshold voltage (Low)			5,4	V
$R_{IN}$	input resistance	10			kΩ
$t_{d(on)IO}$	input-output turn-on propagation time	20,2			μs
$t_{d(off)IO}$	input-output turn-off propagation time	25,6			μs
$t_pERRRESET$	error memory reset time	300000			μs
$t_{TD}$	top / bottom switch : interlock time				μs
$I_{analogOUT}$	8 V corresponds to max. current of 15 V supply voltage (available when supplied with 24 V)				A
$I_{Vs1outmax}$	output current at pin				mA
$I_{A0max}$	logic low output voltage			0,6	mA
$V_{O1}$	logic high output voltage			30	mA
$V_{OH}$					V
$I_{TRIPSC}$	over current trip level ( $I_{analog OUT} = 10 \text{ V}$ )				A
$I_{TRIPLG}$	ground fault protection				A
$T_{tp}$	over temperature protection	110		120	°C
$U_{DCTRIP}$	trip level of $U_{DC}$ -protection ( $U_{analog OUT} = 9 \text{ V}$ ); (option)				V

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